





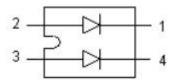
SK2U200-1200 Ultrafast Recovery Modules



Features

- Two fully independent diodes
- Fully insulated package
- Ultrafast, soft reverse recovery, with high operation
- Low forward voltage drop
- Optimized for power conversion: welding and industrial
- SMPS applications
- Easy to use and parallel
- Industry standard outline
- Designed and qualified for industrial level
- Base plate: Nickel plated; Terminals: Nickel plated

Circuit Diagram



Maximum Ratings(limiting values, T_C =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	1200	V
Average Rectified Forward Current	I _F	T _C = 45°C, In DC	100(Per Leg) 200(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I _{FSM}	10 ms, half Sine pulse	800	А







Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 100A, Pulse, pin3->4, T _J = 25 °C	-	1.87	V
	V _{F2}	@ 100A, Pulse, pin2->1, T _J = 25 °C	ı	1.87	V
	V _{F1} - V _{F2}	@100A, T _J = 25 °C	-	0.10	V
	V _{F3}	@ 100A, Pulse, T _J = 125 °C	1.47	1.75	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = \text{rated } V_R$, $T_J = 25 ^{\circ}\text{C}$	0.07	100	uA
	I _{R2}	@V _R = rated V _R ,T _J = 125 °C	0.03	5	mA
Reverse recovery time(Per Leg)	t _{rr}	I_F =500mA, I_R =1A,and I_{rr} =250mA, T_J = 25 °C	131	150	ns
	\ '' \	Ac.50Hz; R.M.S;1min, T _J = 25 °C	-	2500	V
Isolation Breakdown Voltage(R.M.S)	Visol	Ac.50Hz; R.M.S; 1sec, T _J = 25 °C	-	3500	V

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

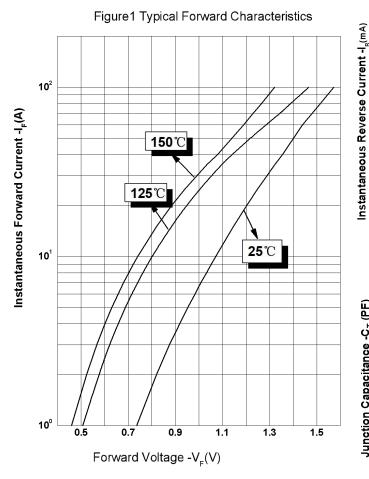
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case(per leg)	R _θ JC	DC operation	0.74	°C/W
Maximum Thermal Resistance Junction to Case(per package)	R _θ JC	DC operation	0.42	°C/W
Mounting torque(M4)	M _D		1.1-1.5/9-13	Nm/
Terminal connection torque(M4)		-	1.1-1.5/9-13	lb.in.
Typical Approximate Weight	wt	-	30	g
Case Style	SOT-227			

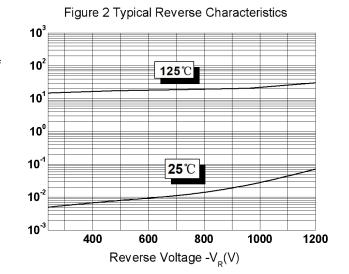


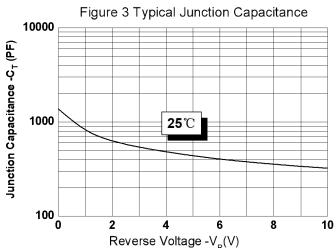




Ratings and Characteristics Curves







[•] China - Germany - Korea - Singapore - United States •

[•] http://www.smc-diodes.com - sales@ smc-diodes.com •



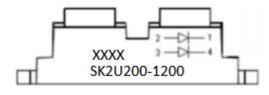




Ordering Information

Device	Package	Shipping
SK2U200-1200	SOT-227	26nas /DLILI/
	(Pb-Free)	36pcs /BULK

Marking Diagram

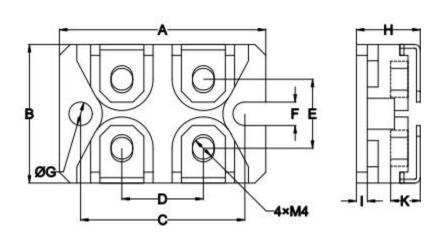


Where XXXX is YYWW

S = SMC's Power Module
K = SOT-227 Package
2 = Circuit Configuration
U = Ultrafast Rectifier
200 = Forward Current (200A)
1200 = Reverse Voltage (1200V)

YY = Year WW = Week

Mechanical Dimensions SOT-227(Millimeters)



SYMBOL	Dimensions in millimeters		
	Min.	Max.	
Α	37.8	38.2	
В	24.8	25.21	
С	29.9	30.55	
D	14.5	15.5	
E	12.2	13.45	
F	4.1	4.31	
G	φ4.1	φ4.31	
Н	11	12.5	
I	1.9	2.1	
K	4.3	6.5	









DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..